

Applications

- Synchronus Rectification
- Industrial and Motor Drive
- DC/DC and AC/DC Converters
- Power Tools

Product Summary

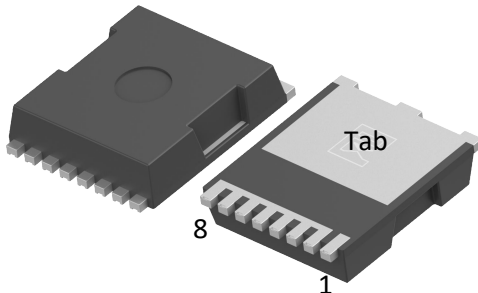
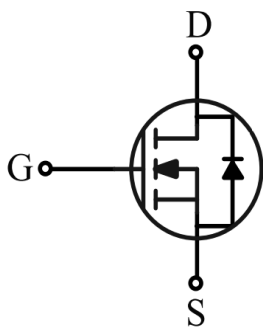
V_{DS}	40	V
I_D	350	A
$R_{DS(ON), Typ@10V}$	1	m Ω
$R_{DS(ON), Typ@4.5V}$	1.5	m Ω
Q_g	85	nC

Features

- High-Speed Switching
- Low $R_{DS(ON)}$
- Enhanced Body diode dv/dt capability
- Enhanced Avalanche Ruggedness
- 100% UIS and RG Tested



TOLL

Gate: Pin1
Drain: Tab
Source: Pin2-8

Package Marking and Ordering Information

Ordering code	Marking	Package	Packaging	Min. package quantity
MT1D2R040SL	MT1D2R040SL	TOLL	Tape & Reel	2000

»» Absolute Maximum Ratings (Tc=25°C unless otherwise noted)

Parameter	Symbol	Ratings	Unit
Drain-Source Voltage	V_{DS}	40	V
Gate-Source Voltage	V_{GS}	±20	V
Continuous Drain Current Tc=25°C (Note 1)	I_D	350	A
Continuous Drain Current Tc=100°C (Note 1)		220	A
Drain Current-Pulsed (Note 1)	I_{DM}	1050	A
Total Dissipation	P_D	250	W
Junction Temperature	T_j	150	°C
Storage Temperature	T_{stg}	-55-150	°C
Single Pulse Avalanche Energy (Note 2)	E_{AS}	1010	mJ

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

»» Thermal Characteristics

Parameter	Symbol	Max	Unit
Maximum Junction-to-Case	$R_{\theta JC}$	0.5	°C/W
Maximum Junction-to-Ambient	$R_{\theta JA}$	40	°C/W

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: $V_{DD}=40V$, $T_{ch}= 25^{\circ}C$ (initial), $L=0.5mH$, $R_g=25\Omega$.

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

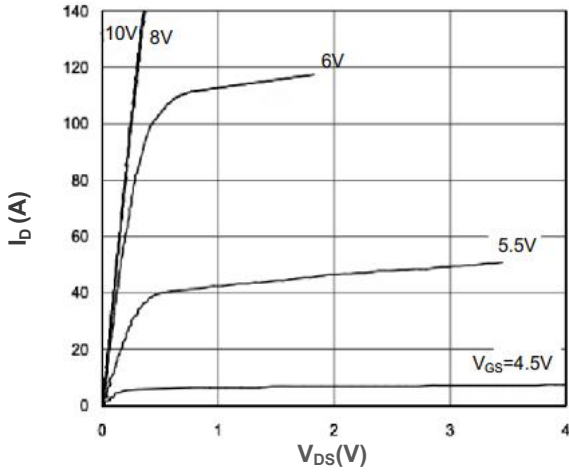


Electrical Characteristics (Tc=25°C unless otherwise noted)

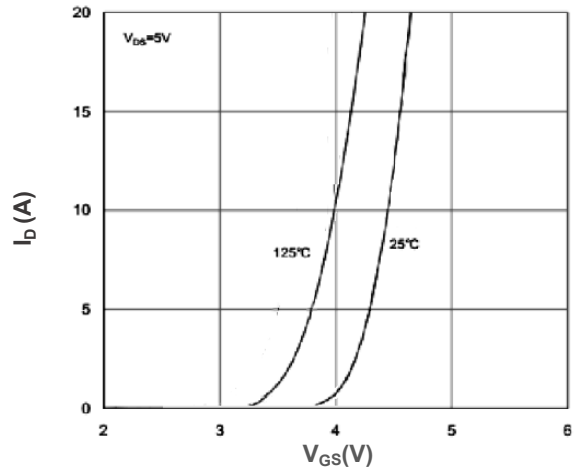
Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Static Parameters						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V, I_D=250\mu A$	40	-	-	V
Drain-Source Leakage Current	I_{DSS}	$V_{DS}=40V, V_{GS}=0V$	-	-	1	μA
Gate-Body Leakage Current	I_{GSS}	$V_{GS}=\pm 20V, V_{DS}=0V$	-	-	± 100	nA
Gate Threshold Voltage	$V_{GS(TH)}$	$V_{GS}=V_{DS}, I_D=250\mu A$	1.1	1.7	2.4	V
Drain-Source On Resistance	$R_{DS(ON)}$	$V_{GS}=4.5V, I_D=15A$	-	1.5	2	m Ω
		Tj=125°C	-	2.2	-	
		$V_{GS}=10V, I_D=20A$	-	1	1.2	
		Tj=125°C	-	1.5	-	
Dynamic Characteristics						
Input Capacitance	C_{ISS}	$V_{DS}=20V, V_{GS}=0V,$ $f=1.0MHz$	-	4935	-	pF
Output Capacitance	C_{OSS}		-	1980	-	pF
Reverse Transfer Capacitance	C_{RSS}		-	236	-	pF
Gate Resistance	R_g	$V_{DS}=0V, V_{GS}=0V,$ $f=1.0MHz$	-	3.8	-	Ω
Switching Paramters						
Turn-On Delay Time	$t_{d(on)}$	$V_{DS}=20V, I_D=20A,$ $V_{GS}=10V, R_L=2\Omega$	-	20	-	ns
Turn-On Rise Time	t_r		-	8	-	ns
Turn-Off Delay Time	$t_{d(off)}$		-	80	-	ns
Turn-Off Fall Time	t_f		-	30	-	ns
Total Gate Charge	Q_g	$V_{DS}=20V, I_D=20A,$ $V_{GS}=10V$	-	85	-	nC
Gate-Source Charge	Q_{gs}		-	14	-	nC
Gate-Drain Charge	Q_{gd}		-	16	-	nC
Source-Drain Characteristics						
Diode Forward Voltage	V_{sd}	$V_{GS}=0V, I_S=10A$	-	0.7	1.2	V
Reverse Recovery Time	t_{rr}	$V_R=40V, I_F=30A,$ $di/dt=500A/\mu s$	-	100	-	ns
Reverse Recovery Charge	Q_{rr}		-	170	-	nC



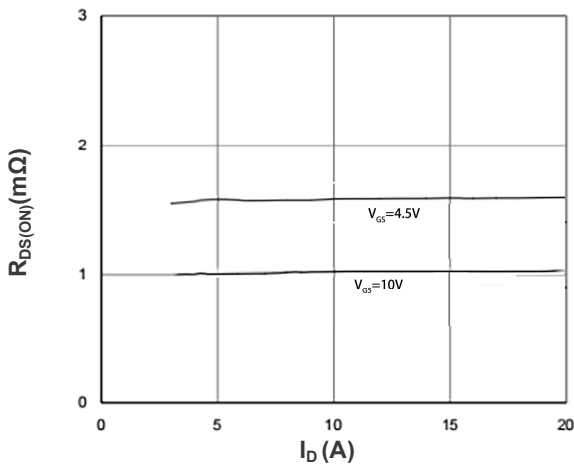
» Characteristics Curves



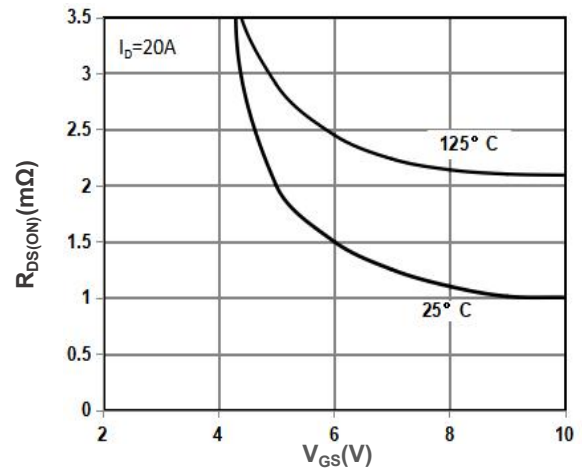
Output Characteristics



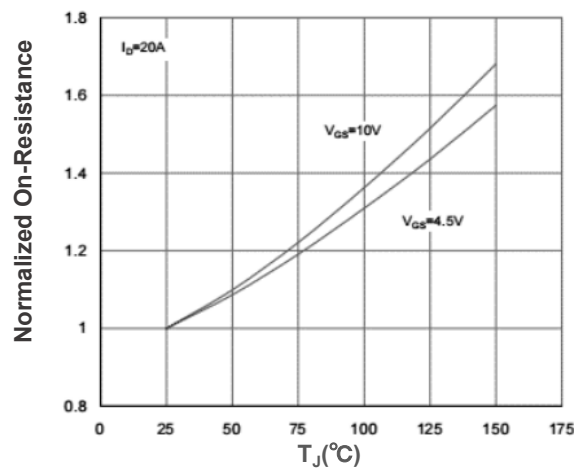
Transfer Characteristics



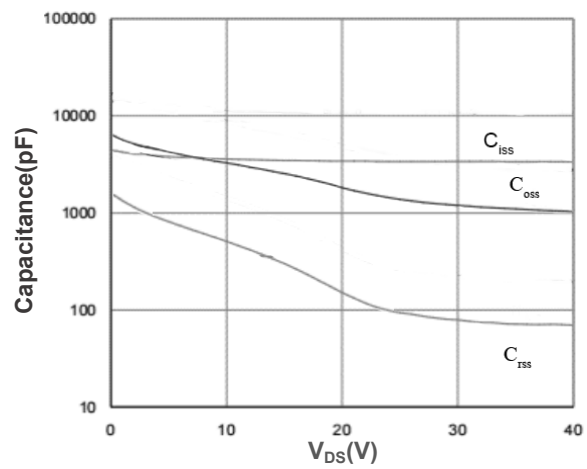
On Resistance Vs Drain Current



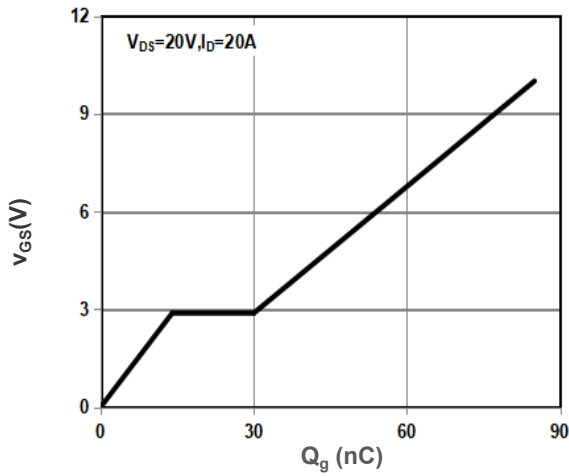
On Resistance Vs Gate Source Voltage



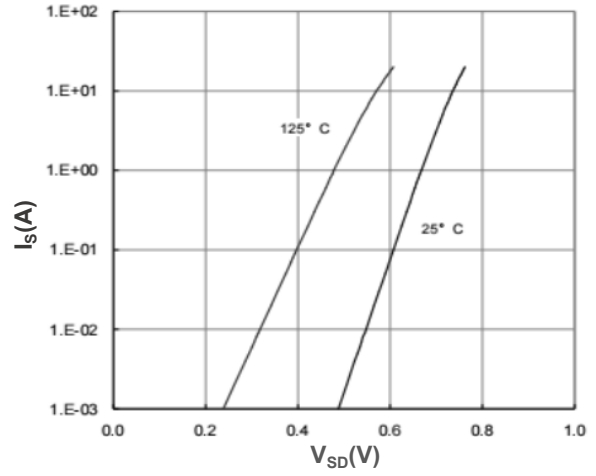
Rdson-JunctionTemperature



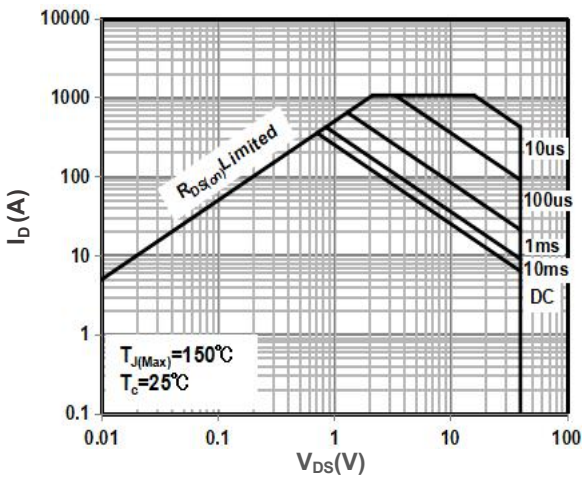
Capacitance



Gate Charge Waveform



Source-Drain Diode Forward Voltage



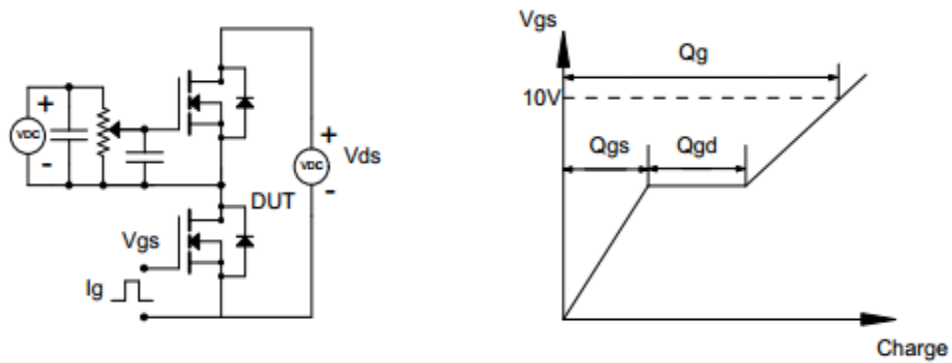
Maximum Safe Operating Area

Note : The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

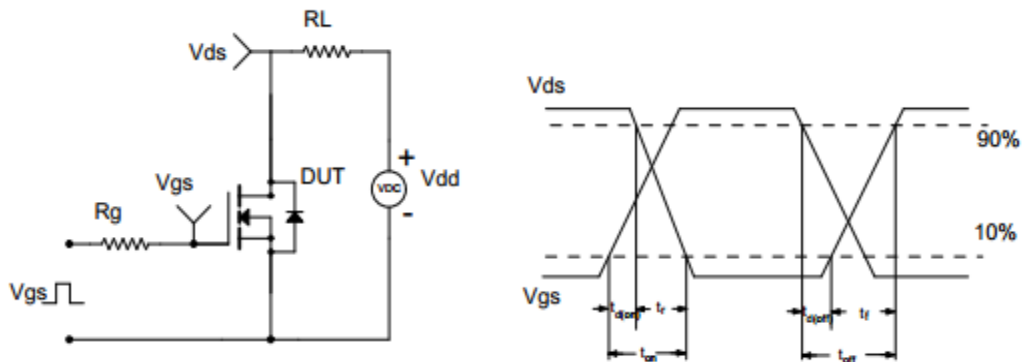


Test Circuit & Waveform

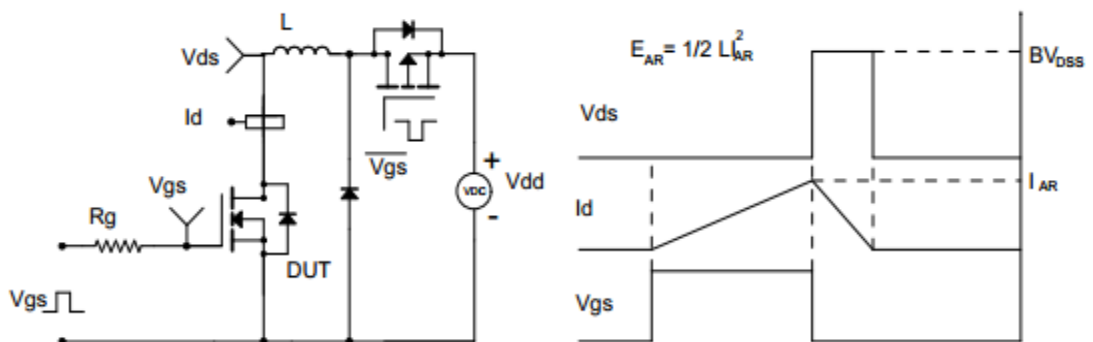
Gate Charge Test Circuit & Waveform



Resistive Switching Test Circuit & Waveform



Unclamped Inductive Switching (UIS) Test Circuit & Waveform





» TOLL Package Dimensions

Unit: mm

Symbol	Min	Nom	Max	Symbol	Min	Nom	Max
A	2.25	2.3	2.35	e1		1.225	
A1	1.75	1.8	1.85	E	9.85	9.9	9.95
b	0.65	0.7	0.75	E1	8	8.1	8.2
b1	9.75	9.8	9.85	H	11.6	11.7	11.8
b2	0.7	0.75	0.8	H1		6.95	
c	0.45	0.5	0.55	K		3.1	
D	10.35	10.4	10.45	L	1.55	1.65	1.75
D1	11	11.1	11.2	L1	0.65	0.7	0.75
D2	3.25	3.3	3.35	L2	0.5	0.6	0.7
D4	4.5	4.55	4.6	Q		7.95	
e		1.2		θ		10°	

